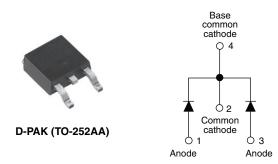
Vishay Semiconductors

Schottky Rectifier, 2 x 3.5 A



PRODUCT SUMMARY							
Package	D-PAK (TO-252AA)						
I _{F(AV)}	2 x 3.5 A						
V _R	60 V						
V _F at I _F	See Electrical table						
I _{RM}	30 mA at 125 °C						
T _J max.	150 °C						
Diode variation	Common cathode						
E _{AS}	6 mJ						

FEATURES

Low forward voltage drop



- Guard ring for enhanced ruggedness and long term reliability
 Halogen-free according to IEC 61249-2-21
 Halogen-free according to IEC 61249-2-21
- definition
- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC

DESCRIPTION

The VS-6CWQ06FN-M3 surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	7	A						
V _{RRM}		60	V						
I _{FSM}	t _p = 5 μs sine	490	A						
V _F	3 Apk, T _J = 25 °C (per leg)	0.61	V						
TJ	Range	- 40 to 150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-6CWQ06FN-M3	UNITS						
Maximum DC reverse voltage	V _R	60	M						
Maximum working peak reverse voltage	V _{RWM}	00	V						

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS					
Maximum average per leg			3.5						
See fig. 5 per device	I _{F(AV)}	50 % duty cycle at T_C = 133 °C, rectangular waveform		7	٨				
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	490	A				
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V_{RRM} applied	70					
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 12 mH		6	mJ				
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1	А				

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PARAMETER	SYMBOL	TEST C	ONDITIONS	VALUES	UNITS	
		3 A	T _{.1} = 25 °C	0.61		
Maximum forward	V _{FM} ⁽¹⁾	6 A	- 1j=25 C	0.76	V	
voltage drop per leg See fig. 1	VFM (')	3 A	T 105 %C	0.53	V	
		6 A	— T _J = 125 °C	0.65		
Maximum reverse	. (1)	T _J = 25 °C		2		
leakage current per leg See fig. 2	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = Rated V _R		mA	
Threshold voltage	V _{F(TO)}	T T mailinear	•	0.38	V	
Forward slope resistance	r _t	$T_J = T_J maximum$		34.31	mΩ	
Typical junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$, (test signal r	145	pF		
Typical series inductance per leg	Ls	Measured lead to lead t	5.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs		

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T_{J} ⁽¹⁾ , T_{Stg}		- 40 to 150	°C			
Maximum thermal resistance,	per leg	Р	DC operation See fig. 4	4.70	°C/W			
junction to case	per device	R _{thJC}		2.35	C/W			
Approximate weight				0.3	g			
				0.01	oz.			
Marking device			Case style D-PAK (similar to TO-252AA)	6CWC	06FN			

Note

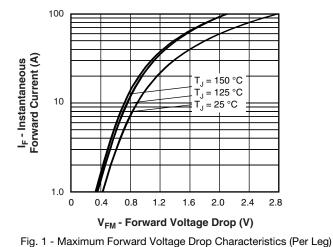
(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



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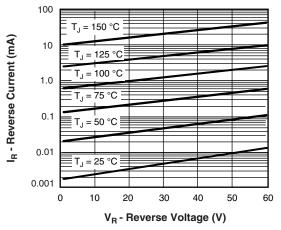


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

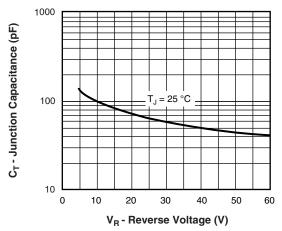


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

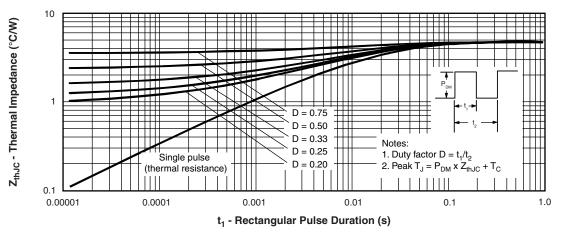


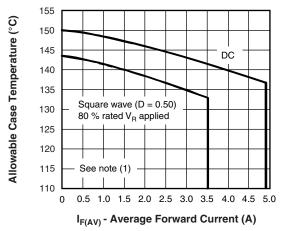
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

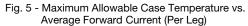
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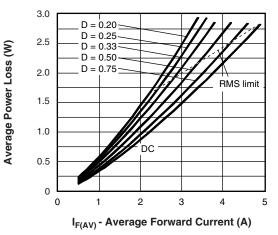


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

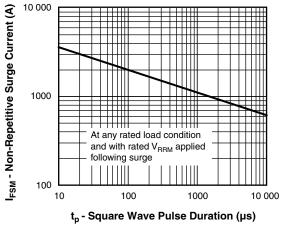


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

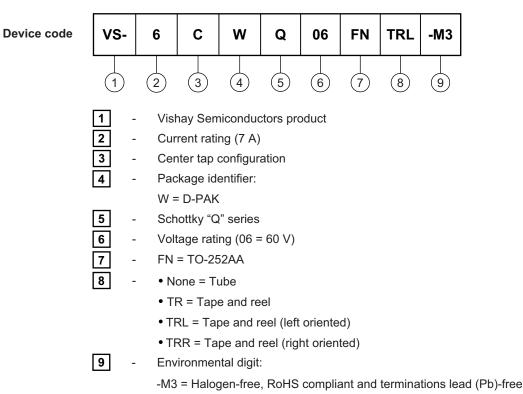
Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 80 % rated V_R



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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-6CWQ06FN-M3	75	3000	Antistatic plastic tube						
VS-6CWQ06FNTR-M3	2000	2000	13" diameter reel						
VS-6CWQ06FNTRL-M3	3000	3000	13" diameter reel						
VS-6CWQ06FNTRR-M3	3000	3000	13" diameter reel						

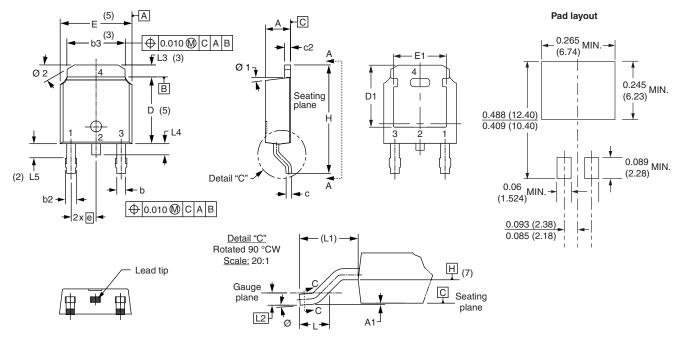
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95016					
Part marking information	www.vishay.com/doc?95176					
Packaging information	www.vishay.com/doc?95033					



Vishay Semiconductors

D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094		е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005		Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035		L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045		L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3	L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024		L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035		L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5	L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3	Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5	Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3	Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

⁽⁴⁾ Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC outline TO-252AA

Document Number: 95016



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